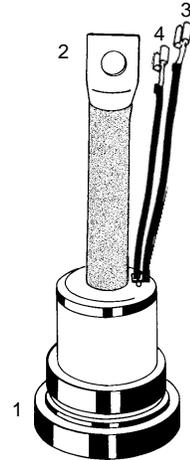
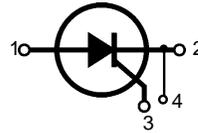


## Phase Control Thyristors

$V_{RRM} = 1200-1800 \text{ V}$   
 $I_{T(RMS)} = 600 \text{ A}$   
 $I_{T(AV)M} = 380 \text{ A}$

$V_{RSM}$ $V_{DSM}$ V	$V_{RRM}$ $V_{DRM}$ V	Type
1300	1200	CS 300-12io3
1700	1600	CS 300-16io3
1900	1800	CS 300-18io3

Not for new application



1 = Anode, 2 = Cathode,  
3 = Gate, 4 = Auxiliary Cathode

Symbol	Test Conditions	Maximum Ratings
$I_{T(RMS)}$	$T_{VJ} = T_{VJM}$	600 A
$I_{T(AV)M}$	$T_{case} = 85^{\circ}\text{C}; 180^{\circ}$ sine	330 A
	$T_{case} = 75^{\circ}\text{C}; 180^{\circ}$ sine	380 A
$I_{TSM}$	$T_{VJ} = 45^{\circ}\text{C};$ $V_R = 0$	t = 10 ms (50 Hz), sine 8500 A t = 8.3 ms (60 Hz), sine 9000 A
	$T_{VJ} = T_{VJM}$ $V_R = 0$	t = 10 ms (50 Hz), sine 8000 A t = 8.3 ms (60 Hz), sine 8500 A
$I^2t$	$T_{VJ} = 45^{\circ}\text{C}$ $V_R = 0$	t = 10 ms (50 Hz), sine 360 000 A <sup>2</sup> s t = 8.3 ms (60 Hz), sine 340 000 A <sup>2</sup> s
	$T_{VJ} = T_{VJM}$ $V_R = 0$	t = 10 ms (50 Hz), sine 320 000 A <sup>2</sup> s t = 8.3 ms (60 Hz), sine 303 500 A <sup>2</sup> s
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$ f = 50 Hz, $t_p = 200 \mu\text{s}$ $V_D = 2/3 V_{DRM}$ $I_G = 1 \text{ A}$ $di_G/dt = 1 \text{ A}/\mu\text{s}$	repetitive, $I_T = 1000 \text{ A}$ 100 A/ $\mu\text{s}$ non repetitive, $I_T = I_{T(AV)M}$ 500 A/ $\mu\text{s}$
$(dv/dt)_{cr}$	$T_{VJ} = T_{VJM}$ $R_{GK} = \infty$ ; method 1 (linear voltage rise)	$V_{DR} = 2/3 V_{DRM}$ 1000 V/ $\mu\text{s}$
$P_{GM}$	$T_{VJ} = T_{VJM}$ $I_T = I_{T(AV)M}$	$t_p = 30 \mu\text{s}$ 120 W $t_p = 10 \text{ ms}$ 10 W
$V_{RGM}$		10 V
$T_{VJ}$		-40...+125 °C
$T_{VJM}$		125 °C
$T_{stg}$		-40...+125 °C
$M_d$	Mounting torque	3.5 Nm 31 lb.in.
Weight		500 g

### Features

- Thyristor for line frequencies
- International flat base package
- Planar glassivated chip
- Long-term stability of blocking currents and voltages

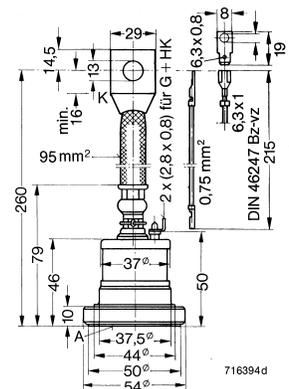
### Applications

- Motor control
- Power converter
- AC power controller

### Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling

### Dimensions in mm (1 mm = 0.0394")



Data according to IEC 60747  
IXYS reserves the right to change limits, test conditions and dimensions

Symbol	Test Conditions	Characteristic Values
$I_R, I_D$	$T_{VJ} = T_{VJM}; V_R = V_{RRM}; V_D = V_{DRM}$	$\leq 40$ mA
$V_T$	$I_T = 1000$ A; $T_{VJ} = 25^\circ\text{C}$	$\leq 1.43$ V
$V_{TO}$	For power-loss calculations only ( $T_{VJ} = 125^\circ\text{C}$ )	1.0 V
$r_T$		0.43 m $\Omega$
$V_{GT}$	$V_D = 6$ V; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$	$\leq 2.0$ V $\leq 2.8$ V
$I_{GT}$	$V_D = 6$ V; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$	$\leq 150$ mA $\leq 250$ mA
$V_{GD}$	$T_{VJ} = T_{VJM}; V_D = 2/3 V_{DRM}$	$\leq 0.2$ V
$I_{GD}$		$\leq 1$ mA
$I_L$	$T_{VJ} = 25^\circ\text{C}; t_p = 10$ $\mu\text{s}$ $I_G = 0.7$ A; $di_G/dt = 0.7$ A/ $\mu\text{s}$	$\leq 100$ mA
$I_H$	$T_{VJ} = 25^\circ\text{C}; V_D = 6$ V; $R_{GK} = \infty$	$\leq 100$ mA
$t_{gd}$	$T_{VJ} = 25^\circ\text{C}; V_D = 1/2 V_{DRM}$ $I_G = 0.7$ A; $di_G/dt = 0.7$ A/ $\mu\text{s}$	$\leq 2$ $\mu\text{s}$
$t_q$	$T_{VJ} = T_{VJM}; I_T = 330$ A, $t_p = 300$ $\mu\text{s}$ ; $di/dt = -20$ A/ $\mu\text{s}$ typ. $V_R = 100$ V; $dv/dt = 20$ V/ $\mu\text{s}$ ; $V_D = 2/3 V_{DRM}$	150 $\mu\text{s}$
$R_{thJC}$	DC current	0.09 K/W
$R_{thJH}$	DC current	0.12 K/W
$d_S$	Creepage distance on surface	1.55 mm
$d_A$	Strike distance through air	1.55 mm
$a$	Max. acceleration, 50 Hz	50 m/s <sup>2</sup>

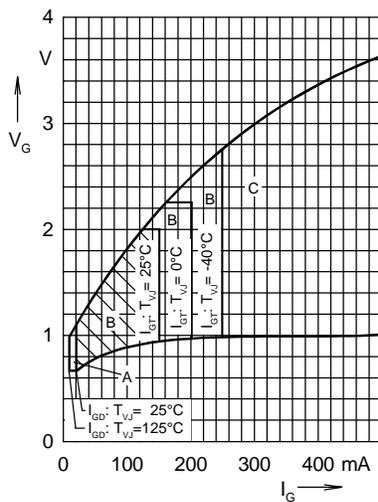


Fig. 1 Gate voltage and gate current  
Triggering:  
A = no; B = possible; C = safe

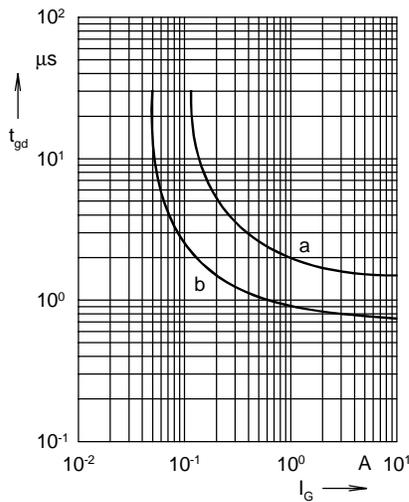


Fig. 2 Gate controlled delay time  $t_{gd}$   
a = limit; b = typical

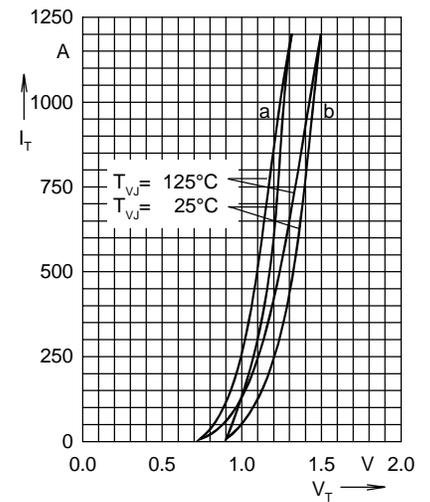


Fig. 3 On-state characteristics  
a = typical; b = limit

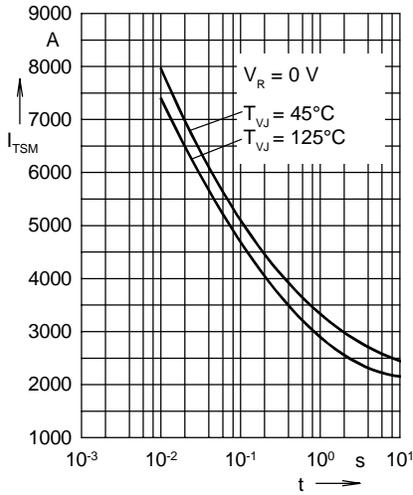


Fig. 4 Surge overload current  
 $I_{TSM}$ : crest value,  $t$ : duration

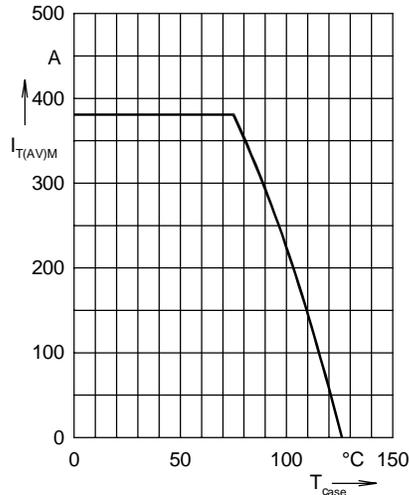


Fig. 5 Maximum forward current at case temperature 180° sine

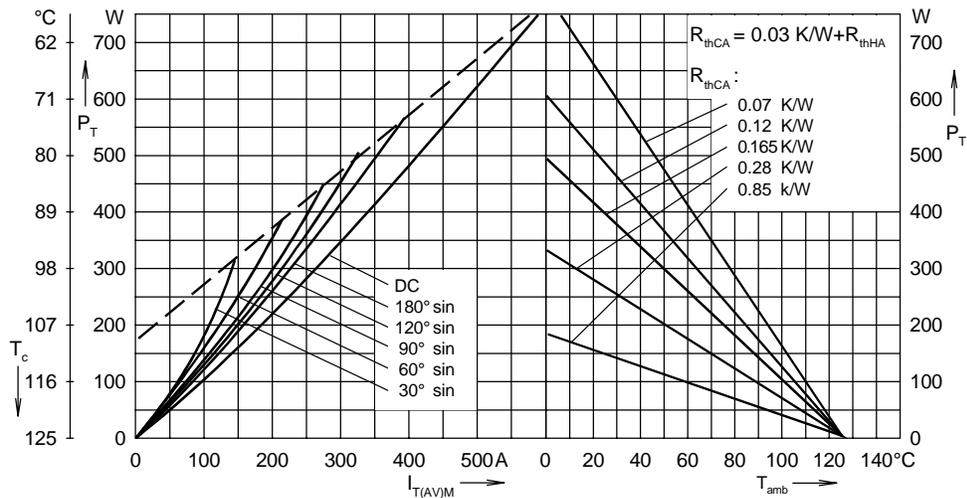


Fig. 6 Power dissipation versus on-state current and ambient temperature (sinusoidal current)

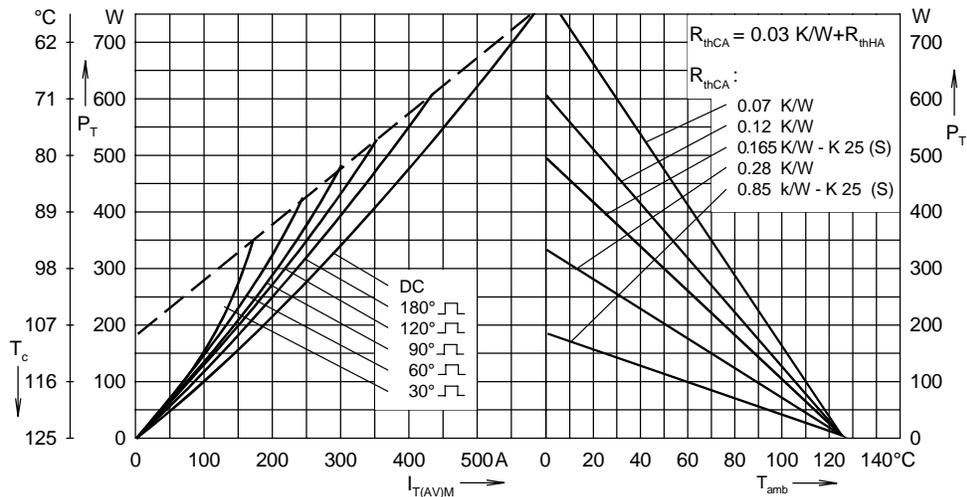


Fig. 7 Power dissipation versus on-state current and ambient temperature (rectangular current)